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1. Introduction

With the rapid development of modern industrialization, environmental pollution, especially water pollution, has become a deadly threat to human health and environmental security due to its long-term harm to human beings and aquatic organisms.¹⁻³ Traditional techniques such as physical,⁴ chemical⁵ and biological methods⁶ for eliminating residual organic contaminants from water suffer from inefficiency and secondary pollution. Nowadays, photocatalysis, as a green technology, has been widely accepted as a potential alternative method for energy conversion and environmental governance due to its high efficiency and environmentally friendliness.⁷⁻⁹ Unfortunately, insufficient utilization of visible light restricts

In situ fabrication of a novel CdS/ZnIn₂S₄/g-C₃N₄ ternary heterojunction with enhanced visible-light photocatalytic performance[†]

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In this study, a novel $g-C_3N_4$ -based ternary heterojunction was rationally designed and constructed by the *in situ* growth of Znln₂S₄ nanosheets and CdS nanoparticles onto the $g-C_3N_4$ nanosheets using a facile two-step oil-bath method. Through optimizing the proportion of Znln₂S₄ and CdS component, $g-C_3N_4$ nanosheets coupled with Znln₂S₄ nanosheets and CdS nanoparticles (denoted as CdS/Znln₂S₄/g-C₃N₄) exhibited obviously higher photocatalytic properties for RhB removal than the single-component and dual-component systems. Among the as-obtained ternary photocatalyts, it was found that the ternary CdS/Znln₂S₄/g-C₃N₄-0.2 photocatalyst displayed the optimum photocatalytic property (96%) within a short time (30 min), which was almost 27.42 and 1.17 times higher than that of pure g-C₃N₄ and binary Znln₂S₄/g-C₃N₄ -0.7 composite. The excellent activity of the ternary CdS/Znln₂S₄/g-C₃N₄ heterostructure is assigned to the synergetic effects of CdS nanoparticles, Znln₂S₄ nanosheets and g-C₃N₄ nanosheets, which not only broaden the visible-light absorption range, but also improve the charge mobility and separation rate, thus boosting the visible-light-driven photocatalytic property of g-C₃N₄.

the practical application of conventional photocatalysts such as TiO_2 and $ZnO.^{10,11}$ Thus, the development of efficient visiblelight-responsive photocatalysts is still greatly desired.

In recent years, the use of two-dimensional (2D) metal-free graphite carbon nitride $(g-C_3N_4)$ in the field of visible-light photocatalysis for hydrogen production,^{12,13} CO₂ reduction^{14,15} and organic pollutants degradation^{16,17} has attracted extensive attention owing to its excellent stability and environment friendly preparation process. Nonetheless, the pristine g-C₃N₄ still suffers from poor separation of the photo-induced charge carriers and insufficient absorption of visible light, which severely restrict its actual application.18,19 Various strategies, such as construction of heterojunctions,^{20,21} elements doping,^{22,23} and morphologies regulation,^{24,25} have been proposed to control and modify g-C₃N₄. Of which, construction of heterojunctions with other narrowband-gap semiconductors is designated as an effective strategy to overcome the above-mentioned shortcomings of unitary g- C_3N_4 .^{26,27} Indium zinc sulfide (ZnIn₂S₄), as a ternary chalcogenide, has been widely used in the field of photocatalysis owing to wide visible-light response range, excellent photoelectric properties, and remarkable chemical stability.28,29 More importantly, ZnIn2S4 possesses an appropriate bandgap structure, which can match well with g-C₃N₄.³⁰ Actually, the construction of ZnIn₂S₄/g-C₃N₄ heterojunction has been proved to be an effective measure to achieve high separation and migration efficiency of photogenerated carriers.31 Additionally, cadmium sulphide (CdS) is also an attractive candidate to couple with g-C₃N₄ for constructing the heterojunction photocatalyst owing to its excellent

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[†] Electronic supplementary information (ESI) available: The XRD patterns of ZnIn₂S₄/g-C₃N₄ composites, XPS survey spectrum and EDS element mappings of CdS/ZnIn₂S₄/g-C₃N₄-0.2, XRD spectra and SEM image of CdS/ZnIn₂S₄/g-C₃N₄-0.2 during a four-cycle experiment. See DOI: https://doi.org/10.1039/d2ra06328j

electronic and structural properties.^{32,33} Recently, CdS is widely used as a promoter decorating the main catalyst to further enhance the photocatalytic properties of the ternary heterostructures such as CdS/ZnIn₂S₄/TiO₂,³⁴ CdS-g-C₃N₄-GA³⁵ and CdS/ Bi₂₀TiO₃₂/Bi₄Ti₃O₁₂.³⁶ Thus, we expect the introduction of CdS nanoparticles to the binary ZnIn₂S₄/g-C₃N₄ heterojunction will further enhance the photocatalytic property of g-C₃N₄.

In this work, we designed and prepared a novel ternarycomponent CdS/ZnIn₂S₄/g-C₃N₄ heterojunction *via* thermal polymerization followed by a two-step *in situ* deposition method. The photocatalytic property of the as-obtained ternary samples was investigated *via* degrading contaminant Rhodamine B (RhB) under visible light irradiation. Owing to the rational construction of ternary composite, CdS/ZnIn₂S₄/g-C₃N₄ revealed a faster transfer and separation rate of photo-induced charge carriers as well as a wider visible-light response range compared to that of g-C₃N₄ and ZnIn₂S₄/g-C₃N₄-0.7, and thus obtaining obvious higher photocatalytic activity. Finally, the underlying mechanism of CdS/ZnIn₂S₄/g-C₃N₄ is elucidated in detail to explain the improvement of the photocatalytic property.

2. Materials and methods

2.1. Materials

All the chemicals were of analytical grade and used without pretreatment. Ethylenediamine tetraacetic acid disodium (EDTA-2Na) and zinc chloride (ZnCl₂) were commercially available from Xilong Science Co., Ltd (Guangdong, China). RhB was bought from Aladdin Biochemical Technology Co., Ltd (Shanghai, China). p-Benzoquinone (BQ) and tertiary butyl alcohol (t-BuOH) were purchased from Shanghai Zhanyun Chemical Co., Ltd (Shanghai, China). Absolute ethanol (EtOH) and hydrochloric acid (HCl) were acquired from Kermel Chemical Reagent Co., Ltd (Tianjin, China). Cadmium chloride hemi (pentahydrate) (CdCl₂·2.5H₂O) and indium chloride (InCl₃) were supplied by Macklin Biochemical Co., Ltd (Shanghai, China). Dicyandiamine (DICY), ammonium chloride (NH₄Cl), and thioacetamide (TAA) were originated from Sinopharm Chemical Reagent Co., Ltd (Shanghai, China). Deionized water was used during the experiments.

2.2. Preparation of g-C₃N₄ nanosheets

The g- C_3N_4 nanosheets were obtained *via* a polymerization process according to the literature.³⁷ In detail, 3 g of DICY and 15 g of NH₄Cl were transferred into a 100 mL round flask containing 50 mL of deionized water, and then the mixture was heated at 80 °C until completely evaporated. The obtained white powder underwent calcination at 550 °C for 4 h in a muffle furnace under air. Finally, light yellow powder of g- C_3N_4 nanosheets was obtained.

2.3. Synthesis of ZnIn₂S₄/g-C₃N₄ binary heterojunctions

The $\text{ZnIn}_2\text{S}_4/\text{g-C}_3\text{N}_4$ composites were *in situ* constructed *via* oilbath heating. Typically, 0.2 g of g-C₃N₄ was dispersed in 50 mL of deionized water (pH = 2.5) by ultrasonic. Then calculated quantity of ZnCl₂, InCl₃, and TAA were dissolved in the above

solution *via* magnetic stirring. After that, the mixture was heated at 80 °C for 2 h. After washed by water and ethanol three times as well as dried at 60 °C overnight, the target product was obtained and labelled as $\text{ZnIn}_2\text{S}_4/\text{g-C}_3\text{N}_4$ -*X* (*X* presents the weight percent of ZnIn_2S_4 and $\text{g-C}_3\text{N}_4$). For reference, ZnIn_2S_4 was also prepared by same procedure but in the absence of g-C₃N₄.

2.4. Synthesis of CdS/ZnIn₂S₄/g-C₃N₄ ternary heterojunctions

The synthesis of ternary CdS/ZnIn₂S₄/g-C₃N₄ heterojunctions was performed by another oil-bath heating process. Briefly, 0.015 g of as-obtained ZnIn₂S₄/g-C₃N₄-0.7 was first dispersed in 50 mL of deionized water by magnetic stirring, while 0.05 g CdCl₂·2.5H₂O and 0.02 g of TAA were dispersed into the above solution. Afterward, the mixture was heated at 70 °C for 2 h. After centrifugation, washing and drying, the target product was collected and labeled as CdS/ZnIn₂S₄/g-C₃N₄-Y (*Y* presents the weight percent of CdS and ZnIn₂S₄/g-C₃N₄). For comparison, CdS, CdS/ZnIn₂S₄-0.2, and CdS/g-C₃N₄-0.2 were also prepared by same procedure in the absence of ZnIn₂S₄/g-C₃N₄-0.7, respectively. The detailed process utilized to prepare the CdS/ZnIn₂S₄/g-C₃N₄ composites is depicted in Scheme 1.

2.5. Characterization

The microstructure and morphologies were investigated by Xray diffraction (XRD, XRD-6100), X-ray photoelectron spectroscopy (XPS, ESCALAB 250Xi), scanning electron microscopy (SEM, Zeiss Sigma) and transmission electron microscope (TEM, Tecnai G220 S-TWIN). Light absorption property was evaluated by UV-vis diffuse reflectance spectroscopy (UV-vis DRS, UV-2550). Photoluminescence (PL) spectra (excitation at 320 nm) were implemented on a spectrophotometer (ZolixLSP-X500A). The surface specific areas of the samples were measured by N2 isothermal adsorption-desorption spectroscopy (Autosorb-Iq2, Quantachrome). Photoelectrochemical tests were performed on an electrochemical station (CHI660E) three-electrode cell system using 500 W Xe lamp as light source. The total organic carbon (TOC) measures were performed on a TOC analyser (TOC-2000, Metash). Electron spin resonance (ESR) spectra were acquired using an EMXnano spectrometer (Bruker)



 $\label{eq:scheme1} \begin{array}{l} \mbox{Scheme1} & \mbox{The formation procedure of } CdS/Znln_2S_4/g-C_3N_4 \mbox{ ternary photocatalysts.} \end{array}$

2.6. Evaluation of the photocatalytic activity

The photodegradation properties were evaluated by using RhB as simulated organic pollutants under the visible light irradiation provided by a 500 W Xe lamp with a cutoff filter ($\lambda \ge 420$ nm). Shortly, photocatalysts (20 mg) were dispersed in fresh RhB aqueous solution (50 mL, 50 mg L^{-1}) and stirred for 60 min in a dark environment to realize the saturation adsorption prior to the light irradiation. After given intervals, aliquots (~3 mL) were taken out, filtered by 0.22 µm filter membrane, and traced absorbance change at 554 nm on a UV-vis spectrophotometer (Lambda 35, PerkinElmer). Furthermore, the reusability of CdS/ ZnIn₂S₄/g-C₃N₄-0.2 was also investigated by recycled photocatalytic experiments.

3. Results and discussion

The purity and crystalline nature of the specimen series were firstly analyzed by XRD. As displayed in Fig. 1 and S1,† the characteristic pattern of the pure g-C₃N₄ are assigned to the graphite-like hexagonal phase, which ascribes well to JCPDS card no. 87-1526.38 The observed diffraction peaks of pristine ZnIn₂S₄ were attributed to hexagonal crystal structure (JCPDS no. 72-0773).39 The diffraction peaks of bare CdS matched well with reported value by JCPDS no. 77-2306.40 For the binary ZnIn₂S₄/g-C₃N₄, CdS/ZnIn₂S₄ or CdS/g-C₃N₄ photocatalysts, the XRD spectra can well indexed to g-C₃N₄ and ZnIn₂S₄ or CdS, which reflects the coexistence of two phases. After CdS was further incorporated into ZnIn₂S₄/g-C₃N₄-0.7 composite, several typical peaks of CdS appear, revealing that CdS was successfully presented in CdS/ZnIn₂S₄/g-C₃N₄ composite. With the increase of ZnIn₂S₄ content in the binary ZnIn₂S₄/g-C₃N₄ composites (Fig. S1[†]) and CdS content in the ternary CdS/ZnIn₂S₄/g-C₃N₄ composites (Fig. 1), the peak intensity of $ZnIn_2S_4$ and CdS gradually increased, respectively. Simultaneously, it can be seen that the diffraction peak of $g-C_3N_4$ (002) is appearing at almost same position of the diffraction peaks of ZnIn₂S₄ (102), CdS (002), and CdS (101), so as to the peak belonging to $g-C_3N_4$ is



Fig. 1 The XRD patterns of $g-C_3N_4$, $ZnIn_2S_4$, CdS, CdS/ $g-C_3N_4$ -0.2, CdS/ZnIn₂S₄-0.2, ZnIn₂S₄/g-C₃N₄-0.7 and CdS/ZnIn₂S₄/g-C₃N₄-Y (Y = 0.1, 0.2 and 0.3)

possibly overlapping of the ZnIn₂S₄ (102), CdS (002), and CdS (101) peaks, and thus possessing a distinguishable diffraction widening. Besides, no other peaks could be detected in the XRD spectra of single-component, binary-component, and ternarycomponent photocatalysts, indicating that there are no impurities produced during the synthesis.

The surface chemical composition and valence state of CdS/ $ZnIn_2S_4/g-C_3N_4-0.2$ were further evaluated by XPS. As depicted in Fig. S2,† the survey XPS spectrum declared the co-occurrence of Cd, S, Zn, In, S, C and N elements in the ternary sample. In the C 1s spectrum (Fig. 2a), the peaks centered at 288.1 and 284.8 eV could be ascribed to graphitic carbon (C=C) and sp²hybridized carbon (N-C=N), respectively.⁴¹ For N 1s (Fig. 2b), the binding energies of peaks at 398.4, 399.5, and 400.7 eV are derived from sp²-hybridized nitrogen (C-N=C), tertiary nitrogen N-(C)₃ groups and amino functions carrying hydrogen (C-N-H), separately.42 The S 2p XPS regions could be deconvoluted into two peaks at 161.6 eV (S $2p_{3/2}$) and 162.9 eV (S $2p_{1/2}$) seen in Fig. 2c, which implies the existence of S^{2-} ions in the ternary composite.43 The high-resolution XPS spectrum of Zn 2p (Fig. 2d) displayed two significant peaks located at 1044.7 eV (Zn $(2p_{1/2})$ and 1021.6 eV (Zn $(2p_{3/2})$), which corresponded to the Zn²⁺ state.44 The In 3d XPS spectrum shows two characteristic peaks at 444.7 and 452.3 eV, corresponding to In 3d_{5/2} and In 3d_{3/2} of In³⁺ in ZnIn₂S₄ (Fig. 2e).⁴⁵ The Cd 3d XPS spectrum reveals two strong peaks at 406.0 (Cd 3d_{5/2}) and 412.5 eV (Cd 3d_{3/2}), which are ascribed to the state of Cd²⁺ (Fig. 2f).⁴⁶

The morphology and microstructures of as-obtained photocatalysts were systematically characterized via SEM and TEM, and the results are depicted in Fig. 3. Fig. 3a shows the morphology of as-constructed g-C₃N₄ with irregular nanosheets. In Fig. 3b, the pure ZnIn₂S₄ with hierarchical flowerlike architecture consisted of thin nanosheets is also successfully constructed via a simple oil-bath method. As for ZnIn₂S₄/g-C₃N₄-0.7 (Fig. 3c), ZnIn₂S₄ nanosheets uniformly disperse on the surface of g-C₃N₄, meaning that a typical 2D/2D heterojunction forms between ZnIn₂S₄ and g-C₃N₄. The SEM image (Fig. 3d) of CdS/ ZnIn₂S₄/g-C₃N₄-0.2 clearly shows a laminated structure consisting of ZnIn₂S₄ nanosheets and g-C₃N₄ nanosheets. Nevertheless, CdS nanoparticles cannot be clearly distinguished, which may be ascribed to the small particle size of CdS, the



Fig. 2 The XPS spectra of CdS/ZnIn₂S₄/g-C₃N₄-0.2: C 1s (a), N 1s (b), S 2p (c), Zn 2p (d), In 3d (e), and Cd 3d (f).



Fig. 3 SEM images of $g-C_3N_4$ (a), $ZnIn_2S_4$ (b), $ZnIn_2S_4/g-C_3N_4-0.7$ (c), and CdS/ZnIn_2S_4/g-C_3N_4-0.2 (d); TEM (e) and HR-TEM (f) images of CdS/ZnIn_2S_4/g-C_3N_4-0.2.

corresponding energy-dispersive system (EDS) element mappings (Fig. S3†) indicate the simultaneous existence and even distribution of g-C₃N₄, ZnIn₂S₄, and CdS. Fig. 3e shows the TEM image of CdS/ZnIn₂S₄/g-C₃N₄-0.2 heterojunction, which consists of g-C₃N₄ nanosheets, ZnIn₂S₄ nanosheets, and CdS nanoparticles. High resolution TEM (HR-TEM) image (Fig. 3f) displays the lattice fringes space of 0.32 and 0.31 nm corresponded to the (102) plane of ZnIn₂S₄ and (101) plane of CdS, separately.^{47,48} These results further confirm the successful construction of target product.

Commonly, large specific surface areas may provide abundant surface active sites for the absorption of reactant molecules, and thus boosting the photocatalytic property.49 Thereby, the specific surface area and pore volume distribution of g-C₃N₄, ZnIn₂S₄/g-C₃N₄-0.7, and CdS/ZnIn₂S₄/g-C₃N₄-0.2 were investigated by N₂ adsorption method. As displayed in Fig. 4a, all three samples show the classical type IV isotherms with the type H₃ hysteresis loops, indicating the existence of mesoporous structure.⁵⁰ The specific surface area (Fig. 4a, inset) of pristine g- C_3N_4 is 25.186 m² g⁻¹. After successively coupling with ZnIn₂S₄ and CdS, the specific surface area of g-C₃N₄ increases from 25.186 m² g⁻¹ to 40.944 and 49.175 m² g⁻¹, which suggests that ZnIn₂S₄ and CdS can obviously improve the BET surface area of g-C₃N₄ providing more active sites for photocatalysis. Moreover, the pore size distributions are displayed in Fig. 4b, the results show that the pore sizes (Fig. 4b, inset) of all three samples distribute at 2-10 nm, which further confirm the presence of mesopores, the mesoporous characteristics are beneficial for producing high surface areas.



Fig. 4 N_2 adsorption-desorption isotherms (a) and the corresponding pore size distribution plots (b) of $g-C_3N_4$, $Znln_2S_4/g-C_3N_4-0.7$ and CdS/Znln_2S_4/g-C_3N_4-0.2.



Fig. 5 UV-vis DRS of $g-C_3N_4$, Znln₂S₄, CdS, Znln₂S₄/ $g-C_3N_4$ -0.7 and CdS/Znln₂S₄/ $g-C_3N_4$ -0.2 (a); the band gap (b), VB-XPS (c), and energy band structure (d) of $g-C_3N_4$, Znln₂S₄, CdS.

The light absorption capacity of the g-C₃N₄, ZnIn₂S₄, CdS, ZnIn₂S₄/g-C₃N₄-0.7 and CdS/ZnIn₂S₄/g-C₃N₄-0.2 photocatalysts was investigated by UV-vis DRS, and the related results are depicted in Fig. 5. Based on the results displayed in Fig. 5a, the light absorption thresholds of g-C₃N₄, ZnIn₂S₄, and CdS are approximately 446 and 500, 562 nm, separately, which are basically in accord with the previous reports.^{51,52} After in situ growing ZnIn₂S₄ and CdS on g-C₃N₄, the light absorption threshold of the ZnIn₂S₄/g-C₃N₄-0.7 and CdS/ZnIn₂S₄/g-C₃N₄-0.2 heterojunctions have significant red shifts, indicating that the combination of ZnIn₂S₄ and CdS can effectively widen the light absorption range of g-C₃N₄. The wider the light absorption range, the more conducive it is to utilize visible light, which is more beneficial to enhance the photocatalytic performance. Fig. 5b shows the bandgap energies (E_g) of g-C₃N₄, ZnIn₂S₄, and CdS estimated by Tauc plot method,53 which are 2.67, 2.40 and 2.36 eV, separately. To further obtain the band edges of $g-C_3N_4$, ZnIn₂S₄, and CdS, their valence band XPS spectra (VB-XPS) were further measured. According to the VB-XPS results depicted in Fig. 5c, the valence band (VB) potentials of g-C₃N₄, ZnIn₂S₄, and CdS are 1.24, 1.51, and 0.83 eV, separately. $E_{\rm g}$ and edge potentials of VB and conduction band (CB) possess the relationship: $E_{g} = E_{VB} - E_{CB}$. As a result, the CB potentials of g-C₃N₄, ZnIn₂S₄, and CdS can be determined as -1.43, -0.89, and -1.53 eV, separately. Accordingly, the overall band structure positions of g-C₃N₄, ZnIn₂S₄, and CdS can be obtained and the results are shown in Fig. 5d.

The internal electron transfer behaviors of photo-induced charge carrier were firstly analyzed by PL technique. As we all know, a lower PL signal represents a higher separation efficiency of photo-generated charge carrier.⁵⁴ As illustrated in Fig. 6a, intense emission peak near 450 nm can be observed for the pristine g- C_3N_4 , indicating an inherent nature of a low separation rate. In contrast, the PL intensity of the $ZnIn_2S_4/g-C_3N_4$ -0.7 and heterojunction obviously quenched. After further coupling with CdS, the obtained CdS/ZnIn_2S_4/g-C_3N_4-0.2 ternary heterojunction displays a lower PL signal, indicating that the charge



Fig. 6 PL spectra (a), transient photocurrent responses (b), and Nyquist plots (c) of g-C₃N₄, ZnIn₂S₄/g-C₃N₄-0.7 and CdS/ZnIn₂S₄/g-C₃N₄-0.2.

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carriers' separation efficiency of g-C₃N₄ can be accelerated by forming ternary heterojunction with ZnIn₂S₄ and CdS. To verify this result, photelectrochemical measurements were performed to support the improved separation and transfer efficiency. Generally, higher photocurrent intensity or smaller semicircle radius means higher separation and transfer efficiency of photo-generated charge carriers.55 As displayed in Fig. 6b, the photocurrent intensity of CdS/ZnIn₂S₄/g-C₃N₄-0.2 composite is obviously higher that of ZnIn₂S₄/g-C₃N₄-0.7 and g-C₃N₄. The results of electrochemical impedance spectroscopy (EIS) (Fig. 6c) show CdS/ZnIn₂S₄/g-C₃N₄-0.2 possesses the lowest charge transfer impedance due to its smaller semicircle radius than the two other samples. The photoelectrochemical results forcefully verify that the constructing of CdS/ZnIn₂S₄/g-C₃N₄-0.2 ternary composite significantly promotes the charge carrier transfer and separation, and thus delivering boosting photocatalytic property.

The visible-light photocatalytic activities of the pristine g-C₃N₄, ZnIn₂S₄, CdS, CdS/g-C₃N₄-0.2, CdS/ZnIn₂S₄-0.2, and a series of ZnIn₂S₄/g-C₃N₄ and CdS/ZnIn₂S₄/g-C₃N₄ composites were evaluated by the degradation of RhB. As depicted in Fig. 7a, the degradation efficiency of ZnIn₂S₄ and CdS is obviously higher than that of g-C₃N₄ due to their wider visible-light response range. The photocatalytic properties of g-C₃N₄ and ZnIn₂S₄ are obviously improved after coupling with ZnIn₂S₄ or CdS. Among of the ZnIn₂S₄/g-C₃N₄ composites, ZnIn₂S₄/g-C₃N₄-0.2 exhibited the highest degradation efficiency of 82% within 30 min. When ZnIn₂S₄/g-C₃N₄-0.2 further coupled with CdS, the photocatalytic activities could be obviously improved. Among the ternary photocatalysts, CdS/ZnIn₂S₄/g-C₃N₄-0.7 exhibited the highest degradation efficiency, in which 96% of RhB could be degradated within 30 min. Moreover, the photocatalytic kinetics of RhB degradation were evaluated using the psedo-first-order model (Fig. 7b). The CdS/ZnIn₂S₄/g-C₃N₄-0.2 showed the highest apparent rate constant, approximately 0.10868 min⁻¹, which is far greater than that of the pristine g- C_3N_4 (0.00043 min⁻¹), $ZnIn_2S_4/g-C_3N_4-0.7$ (0.05475 min⁻¹) and $CdS/g-C_3N_4-0.2$ (0.02580 min⁻¹) under the same conditions, separately. Furthermore, the TOC measurements were also carried out to investigate the mineralization abilities of photocatalysts under 30 min of visible light irradiation. As illustrated in Fig. 7c, the TOC removal efficiency of CdS/ZnIn₂S₄/g-C₃N₄-0.2 (84.65%) is obviously higher than that of $g-C_3N_4$ (0.40%) and $ZnIn_2S_4/g-C_3N_4-0.7$ (73.97%), which is coincident with the trend of photodegradation performance. This result fully confirms the high mineralization ability of $CdS/ZnIn_2S_4/g-C_3N_4-0.2$ for RhB. The stability is a crucial factor affecting the actual application of the photocatalyst,⁵⁶ and thus sequential cycling experiments were performed to detect the stability of the CdS/ ZnIn_2S_4/g-C_3N_4-0.2 ternary photocatalyst. As displayed in Fig. 7d, the photocatalytic efficiency had no obvious change after four reused tests. Besides, the structure and morphology can also be preserved after undergoing four runs of photodegradation reaction as no noticeable change can be observed in the XRD pattern (Fig. S4†) and SEM image (Fig. S5†). The results prove that the as-prepared ternary catalysts can meet the practical application requirements.

To expound the photocatalytic mechanism of the photocatalytic activity improvement of CdS/ZnIn₂S₄/g-C₃N₄ photocatalysts, the predominant active species formed during the photocatalytic process were distinguished *via* a series of trapping experiments over CdS/ZnIn₂S₄/g-C₃N₄-0.2. In the experiments, EDTA-2Na, BQ, and *t*-BuOH were chosen as the scavengers of hydroxyl radicals ('OH), radical superoxide ('O₂⁻), and hole (h⁺), separately. Fig. 8a exhibits the addition of BQ has a significant effect on the degradation activity, which mean that 'O₂⁻ was the primary active substance during the photocatalytic process. However, after adding EDTA-2Na and *t*-BuOH, the



Fig. 7 Visible-light photodegradation of RhB over as-obtained samples (a) and the corresponding kinetics (b); removal rate of TOC by $g-C_3N_4$, $ZnIn_2S_4/g-C_3N_4-0.7$, and $CdS/ZnIn_2S_4/g-C_3N_4-0.2$ for RhB degradation (c); four cycling tests of photocatalytic degradation RhB for CdS/ZnIn_2S_4/g-C_3N_4-0.2 (d).

Fig. 8 Photodegradation of RhB over the CdS/Znln₂S₄/g-C₃N₄-0.2 photocatalyst in the presence of different radical scavengers (a); ESR detection of O_2^- over CdS/Znln₂S₄/g-C₃N₄-0.2 (b).

removal efficiency of RhB decreased from 96% to 90% and 94%, separately, which revealed that h^+ had a weak effect on the photocatalytic reaction, while the role of 'OH could be ignored owing to the negligible effect of EDTA-2Na on the RhB removal efficiency. Consequently, it could be inferred that the active species played a different role during the photocatalytic reaction process with a sequence of $O_2^- > h^+ > OH$. In addition, the ESR results (Fig. 8b) provided a persuasive proof for the existence of O_2^- in the photodegradation reaction. No ESR signals were observed under dark, while the signals of the DMPO- O_2^- adducts (intensity ratio of 1:1:1:1) could be easily identified after irradiating by visible light, which is fully in accord with the results of radical trapping experiments.

Based on the conclusions above, a plausible photocatalytic charge-transfer mechanism of the CdS/ZnIn₂S₄/g-C₃N₄ composite for photocatalytic degradation of RhB is put forward and displayed in Scheme 2. Under the visible light irradiation, g-C₃N₄, ZnIn₂S₄ and CdS can adsorb photons and generate a great deal of photo-induced electrons (e⁻) and h⁺ pairs, where the e⁻ and h⁺ gather at CB and VB, separately. According to the calculated band structure and close contact interface, e⁻ in the CB of CdS can readily migrate to the CB of ZnIn₂S₄ by a one-step process or two-step process. Meanwhile, h⁺ in the VB of ZnIn₂S₄ transfers to the VB of CdS under the driving force of potential difference. Then, the accumulated e⁻ in ZnIn₂S₄ will react with dissolved O₂ to produce 'O₂⁻ due to its more negative potential than O₂/'O₂⁻ (-0.33 eV versus NHE),⁵⁷ while the VB potential of CdS is too low for h⁺ to convert -OH into 'OH (+2.4 eV versus



Scheme 2 Proposed mechanism for the visible-light photodegradation of RhB over CdS/Znln₂S₄/g-C₃N₄ ternary composite.

NHE).⁵⁸ Finally, the O_2^- and h^+ behave as oxidation active site for the degradation of RhB due to their high oxidative capacity.

4 Conclusions

In general, the CdS/ZnIn₂S₄/g-C₃N₄ ternary photocatalyst was prepared by a facile pyrolysis route coupling with simple two-step oil-bath procedure and the photoactivity was evaluated by degrading RhB under visible light irradiation. As expected, CdS/ ZnIn₂S₄/g-C₃N₄ ternary composites possess boosted photocatalytic performance, which is not only higher than bare $g-C_3N_4$, ZnIn₂S₄ and CdS, but also even superior to ZnIn₂S₄/g-C₃N₄ and CdS/g-C₃N₄ binary photocatalysts. Among them, the CdS/ ZnIn₂S₄/g-C₃N₄-0.2 photocatalyst achieves the best photocatalytic activity with a degradation rate of 96%. Additionally, the proposed CdS/ZnIn₂S₄/g-C₃N₄-0.2 composite reveals excellent photostability and reusability after four reused tests. The reasonable construction of ternary heterojunction not only facilitates the photogenerated charge carrier separation and migration as well as widen the visible-light response range, but also enhances the specific surface area, all of which are favorable for photocatalytic process. The design and fabrication of the CdS/ ZnIn₂S₄/g-C₃N₄ ternary heterojunction photocatalysts represent a promising approach to fabricate high efficient g-C₃N₄-based photocatalysts for environmental remediation.

Author contributions

Jingzhe Li: data curation, investigation, writing – original draft. Yue Chen and Liezhen Zhu: investigation, validation, data curation. Linfa Liao and Xinmao Wang: investigation, validation. Xun Xu and Lingfang Qiu: conceptualization, funding acquisition, supervision. Jiangbo Xi: investigation, methodology. Ping Li: conceptualization, methodology, funding acquisition, writing – review & editing, supervision. Shuwang Duo: conceptualization, funding acquisition, project administration, supervision.

Conflicts of interest

There are no conflicts to declare.

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